

Description

The DIODES™ PAM8904E is a piezo sounder driver with integrated charge pump boost converter. The PAM8904E is capable of driving a ceramic/piezo sounder with 27V_{PP} from a 4.5V power supply. The charge pump can operate in either 1x, 2x or 3x mode.

The boost converter operates at a fixed frequency of 100kHz and provides a 3X V_{IN} output with a minimum number of external components. The PAM8904E can drive up to 47nF loading. Diodes Incorporated's unique drive technology provides a small inrush current, low EMI and high efficiency.

The PAM8904E includes built-in automatic shutdown and wake up that guarantees longer battery life. The PAM8904E features thermal shutdown, over current protection, over voltage protection and under voltage lock-out.

The PAM8904E is available in U-QFN3030-16 (Type B), U-QFN3030-12 (Type A), W-QFN2020-12 (Type US) and U-QFN2020-12 (Type UX) packages.

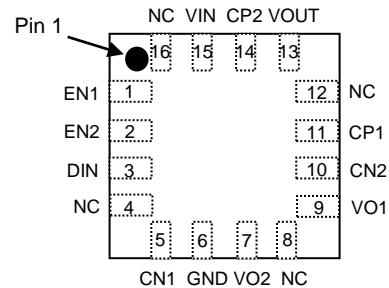
Features

- Supply Voltage Range from 1.5V to 5.5V
- 18V_{PP} Output from a 3V Supply
- Integrated Boost Converter Generates up to 13.5V Supply
- Input Signal 20Hz to 300kHz
- No Voltage Cross Output in Shutdown Mode
- Low Current Consumption
- Automatic Standby and Wake-up Control
- Available in Space Saving U-QFN3030-16 (Type B), U-QFN3030-12 (Type A), W-QFN2020-12 (Type US) and U-QFN2020-12 (Type UX) Packages
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](mailto:contact@diodes.com) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

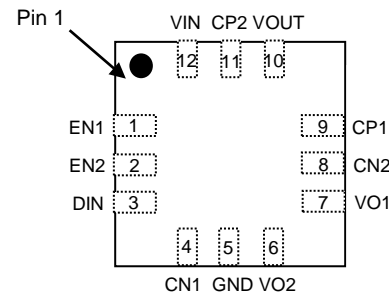
Pin Assignments

U-QFN3030-16 (Type B)



Top View

**U-QFN3030-12 (Type A)/W-QFN2020-12 (Type US)/
U-QFN2020-12 (Type UX)**

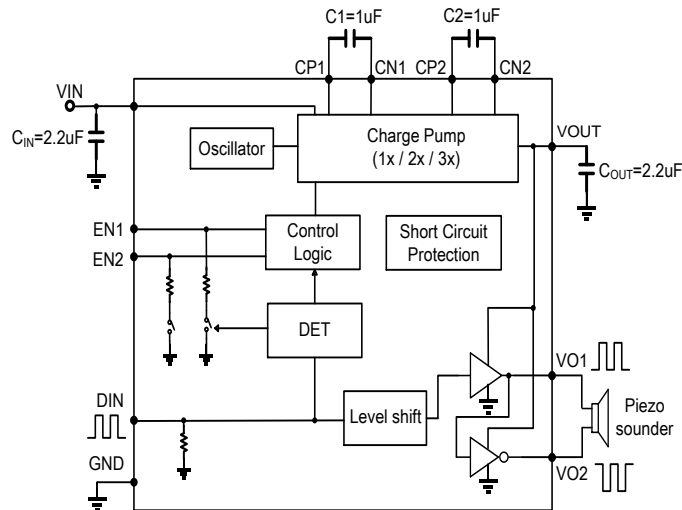


Top View

Applications

- Health care systems
- Alarm clocks
- Security devices
- Home appliances

Typical Applications Circuit



Pin Descriptions

Pin Number		Pin Name	I/O/P	Function
U-QFN3030-16 (Type B)	U-QFN3030-12 (Type A) W-QFN2020-12 (Type US) U-QFN2020-12 (Type UX)			
1	1	EN1	I	Charge Pump Mode Select 1
2	2	EN2	I	Charge Pump Mode Select 2
3	3	DIN	I	Signal Input
4	—	NC	—	No Connection
5	4	CN1	I	Capacitor 1 Negative Terminal
6	5	GND	P	Ground
7	6	VO2	O	Positive Output
8	—	NC	—	No Connection
9	7	VO1	O	Negative Output
10	8	CN2	I	Capacitor 2 Negative Terminal
11	9	CP1	I	Capacitor 1 Positive Terminal
12	—	NC	—	No Connection
13	10	VOUT	O	Boost Output
14	11	CP2	I	Capacitor 2 Positive Terminal
15	12	VIN	P	Power Supply
16	—	NC	—	No Connection

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Symbol	Characteristics	Value	Unit
V _{IN}	Supply Voltage	-0.3 to 6.0	V
V _{OUT}	Output Voltage	15	V
V _{EN1, VEN2}	EN1, EN2 Voltage	GND -0.3 to V _{IN} +0.3	V
T _A	Operating Free-Air Temperature Range	-40 to +85	°C
T _J	Operating Junction Temperature Range	-40 to +150	°C
T _{STG}	Storage Temperature Range	-65 to +150	°C

Recommended Operating Conditions (@T_A = +25°C, unless otherwise specified.)

Symbol	Characteristics	Min	Max	Unit
V _{IN}	Supply Voltage	—	5.5	V
V _{IH}	High-Level Input Voltage	EN1, EN2	0.8*V _{IN} to V _{IN}	V
V _{IL}	Low-Level Input Voltage	EN1, EN2	0.4	V
T _A	Operating Free-Air Temperature	-40	+85	°C

Thermal Information

Symbol	Parameter	Package	Max	Unit
θ _{JA}	Thermal Resistance (Junction to Ambient)	U-QFN3030-16 (Type B)	35	°C/W
		U-QFN3030-12 (Type A)	35	
		U-QFN2020-12 (Type UX)	68	
		W-QFN2020-12 (Type US)	68	
θ _{JC}	Thermal Resistance (Junction to Case)	U-QFN3030-16 (Type B)	14	°C/W
		U-QFN3030-12 (Type A)	14	
		U-QFN2020-12 (Type UX)	25	
		W-QFN2020-12 (Type US)	25	

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, $V_{IN} = 3.0\text{V}$, $C_{PIEZO} = 47\text{nF}$, $f_{DIN} = 3.2\text{kHz}$, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{OUT}	Output Voltage Range	(Note 4)	1.5	—	13.5	V
V_{OUT1}	Output Voltage	1x Mode	2.8	—	3	V
V_{OUT2}		2x Mode	5.2	—	6	V
V_{OUT3}		3x Mode (Note 5)	7.2	—	9	V
V_{OUT4}		3x Mode ($V_{IN} = 2.7\text{V}$)	6.8	7	8.0	V
I_{DD11}		Operating Current 1	1x Mode, $C_{PIEZO} = \text{No Load}$	—	43	—
I_{DD12}	2x Mode, $C_{PIEZO} = \text{No Load}$		—	118	—	μA
I_{DD13}	3x Mode, $C_{PIEZO} = \text{No Load}$		—	220	—	μA
I_{DD21}	Operating Current 2	1x Mode, Single-Ended Application	—	0.48	—	mA
I_{DD22}		2x Mode, Single-Ended Application	—	1.9	—	mA
I_{DD23}		3x Mode, Single-Ended Application	—	4.3	—	mA
I_{DD31}	Operating Current 3	1x Mode, Differential Application	—	1.7	—	mA
I_{DD32}		2x Mode, Differential Application	—	6.4	—	mA
I_{DD33}		3x Mode, Differential Application	—	14.2	—	mA
I_{SD}	Shutdown Current	$DIN = 0\text{V}$	—	0.008	1	μA
f_{IN}	Input Frequency	Rectangular Pulse	—	3.2	—	kHz
f_{OSC}	Oscillating Frequency	—	70	100	130	kHz
t_{ON1}	V_{OUT} Start Delay Time	1x Mode, From DIN Signal High to 90% V_{OUT} Steady State	—	470	—	μs
t_{ON2}		2x Mode, From DIN Signal High to 90% V_{OUT} Steady State	—	1.76	—	ms
t_{ON3}		3x Mode From DIN Signal High to 90% V_{OUT} Steady State	—	1.91	—	ms
t_{OFF}	Shutdown Delay Time	$DIN = H > L$	—	42	—	ms
I_{SC}	Output Short-Circuit Current	—	—	49	—	mA
V_{IH}	Control Terminal Voltage H	EN1, EN2, DIN Pins	$0.8 \cdot V_{IN}$	—	V_{IN}	V
V_{IL}	Control Terminal Voltage L	EN1, EN2, DIN Pins	0	—	$0.2 \cdot V_{IN}$	V
I_{IH1}	Control Terminal Current 1	$DIN = 3\text{V}$	—	—	5	μA
I_{IH2}	Control Terminal Current 2	$V_{EN1}, V_{EN2} = 3\text{V}, DIN = 3\text{V}$	—	—	5	μA
I_{IH3}	Control Terminal Current 3	$V_{EN1}, V_{EN2} = 3\text{V}, DIN = 0\text{V}$	—	—	1	μA

- Notes:
4. It is possible to drive V_{OUT} , V_{O1} and V_{O2} to $3x V_{DD}$. A supply voltage of 4.5V or more should not be used in 3x mode as this will exceed the maximum output voltage rating.
 5. When designed under 3x mode, it should be carefully noted that the V_{OUT} absolute maximum value should not exceed 13.5V.

Application Information

Charge Pump Mode Setting

The Charge Pump Mode (CPM) pins EN1 and EN2 are used to set the charge pump into mode 1x V_{DD}, 2x V_{DD}, 3x V_{DD} or they can be used to put the PAM8904E into a forced low current shutdown mode.

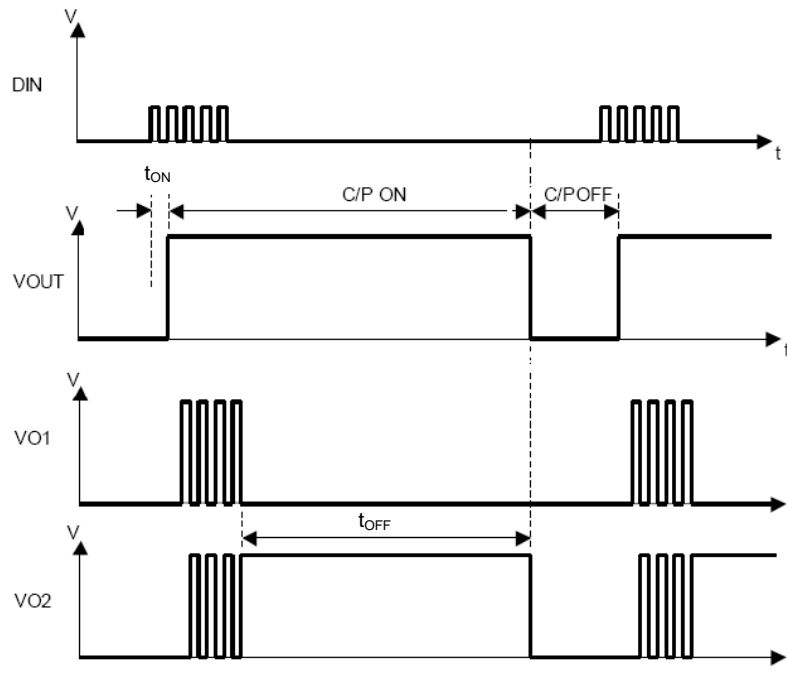
DIN	EN1	EN2	MODE
0	—	—	Shutdown Mode
1	0	0	Shutdown Mode
1	0	1	1x Mode
1	1	0	2x Mode
1	1	1	3x Mode

V _{DD} Range	Mode
1.5V to 4.5V	1x, 2x and 3x
1.5V to 5.5V	1x, 2x

Timing Chart and Device Operation

When one or both of the EN pins are pulled high, the device enters normal operation mode. Refer to the above table for the mode selection. Once the PAM8904E senses a valid signal on the DIN pin, the charge pump will start and provide the desired voltage on the VOUT pin and the output drive VO1 and VO2 start to function after time t_{ON} which is typically between 470μs and 2s depending on the mode chosen. Once the input signal on DIN is removed, the PAM8904E senses this and waits typically 42ms to ensure the signal has been removed. If there is no further valid signal within the time period t_{OFF}, the PAM8904E enters into a low current standby mode.

Timing Chart



Application Information (continued)

Output Configuration

The PAM8904E is able to be configured either in a differential or a single ended configuration.

Short-Circuit Protection

The PAM8904E has short circuit protection circuitry on the outputs to prevent damage. Once a short circuit is detected on the outputs, the chip will limit the total current to protect the output device. This is not a latched fault; once the short is removed, the normal operation is restored.

Thermal Protection

If the junction temperature of the PAM8904E exceeds +150°C, the device will enter overtemperature shutdown. The outputs and the charge pump will be switched off. Once the junction temperature cools down to its normal operating condition, the IC will re-start automatically.

Ordering Information

PAM8904E XXXX

Package and Packing

- JER : U-QFN3030-16 (Type B) with T/R
- JPR : U-QFN3030-12 (Type A) with T/R
- GPR : W-QFN2020-12 (Type US) with T/R
- GPR-T : U-QFN2020-12 (Type UX) with T/R

Part Number	Package	Status	Packing	
			Qty.	Carrier
PAM8904EJER	U-QFN3030-16 (Type B)	NRND (CONTACT US)	3,000	Tape & Reel
PAM8904EJPR	U-QFN3030-12 (Type A)	NRND (CONTACT US)	3,000	Tape & Reel
PAM8904EGPR	W-QFN2020-12 (Type US)	Active	3,000	Tape & Reel
PAM8904EGPR-T	U-QFN2020-12 (Type UX)	Active	3,000	Tape & Reel

NRND: Not Recommended for New Design.

Marking Information

U-QFN3030-16 (Type B)/U-QFN3030-12 (Type A)

(Top View)

P8904E: Product Type Marking Code
 XXX: Internal Code
 Y: Year 0 to 9 (ex: 2 = 2022)
 W: Week: A to Z: Week 1 to 26
 a to z: Week 27 to 52
 z Represents Week 52 and 53

W-QFN2020-12 (Type US)/U-QFN2020-12 (Type UX)

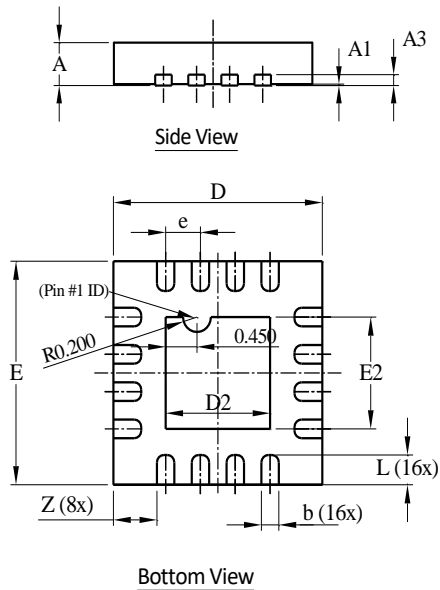
(Top View)

BM: Product Type Marking Code
 XX: Internal Code
 W: Week: A to Z: Week 1 to 26
 a to z: Week 27 to 52
 z Represents Week 52 and 53

Package Outline Dimensions

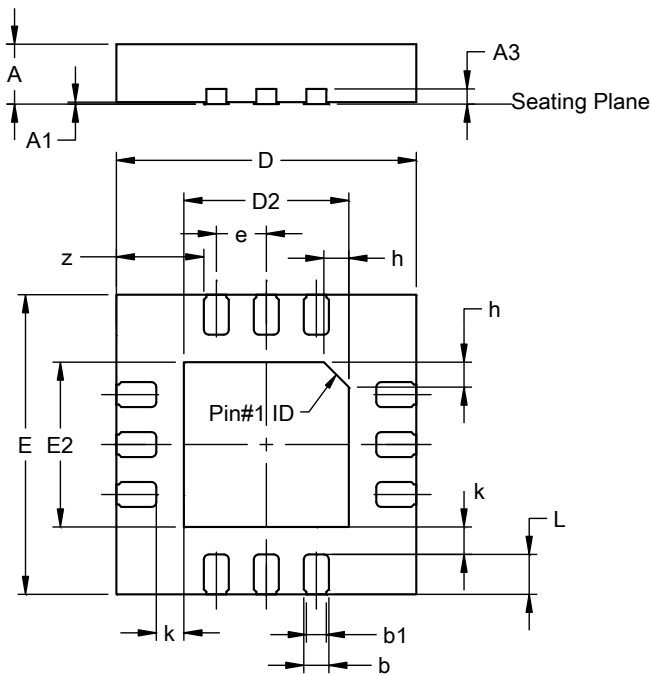
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

(1) Package Type: U-QFN3030-16 (Type B)



U-QFN3030-16 (Type B)			
Dim	Min	Max	Typ
A	0.55	0.65	0.60
A1	0	0.05	0.02
A3	-	-	0.15
b	0.18	0.28	0.23
D	2.95	3.05	3.00
D2	1.40	1.60	1.50
E	2.95	3.05	3.00
E2	1.40	1.60	1.50
e	-	-	0.50
L	0.35	0.45	0.40
Z	-	-	0.625
All Dimensions in mm			

(2) Package Type: U-QFN3030-12 (Type A)

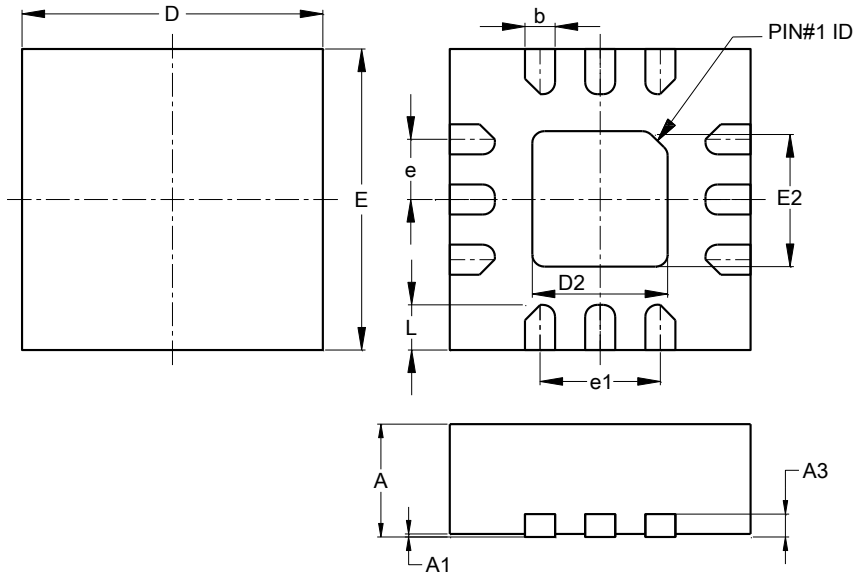


U-QFN3030-12 (Type A)			
Dim	Min	Max	Typ
A	0.55	0.65	0.60
A1	0.00	0.05	0.02
A3	--	--	0.152
b	0.20	0.35	0.25
b1	0.15	0.25	0.20
D	2.95	3.05	3.00
D2	1.55	1.75	1.65
E	2.95	3.05	3.00
E2	1.55	1.75	1.65
e	--	--	0.50
h	--	--	0.25
L	0.35	0.45	0.40
k	--	--	0.275
z	--	--	0.875
All Dimensions in mm			

Package Outline Dimensions (continued)

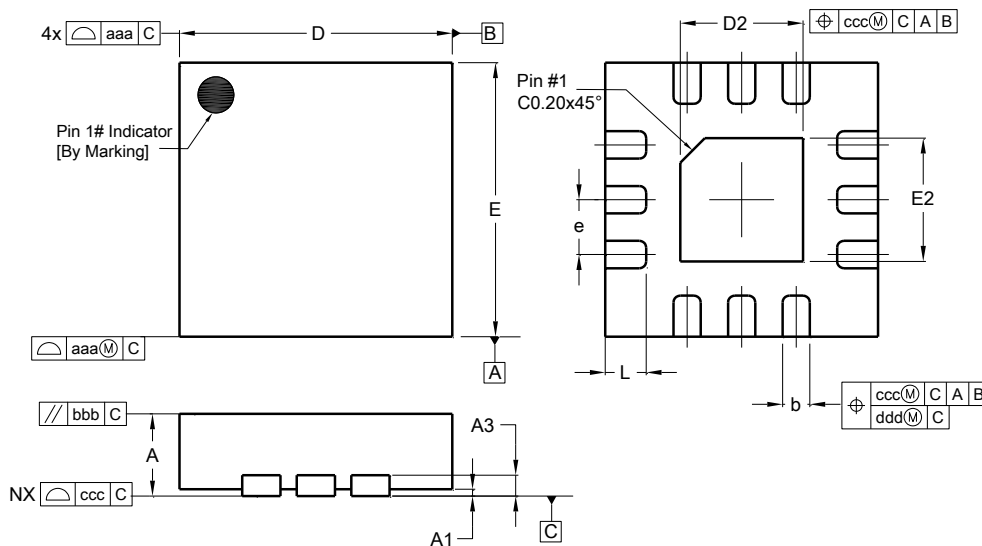
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

(3) Package Type: W-QFN2020-12 (Type US)



W-QFN2020-12 (Type US)			
Dim	Min	Max	Typ
A	0.700	0.800	0.750
A1	0.00	0.050	--
A3	0.203REF		
b	0.150	0.250	0.200
D	1.950	2.050	2.000
D2	0.850	0.950	0.900
E	1.950	2.050	2.000
E2	0.850	0.950	0.900
e	0.400 BSC		
e1	0.800 REF		
L	0.250	0.350	0.300
All Dimensions in mm			

(4) Package Type: U-QFN2020-12 (Type UX)

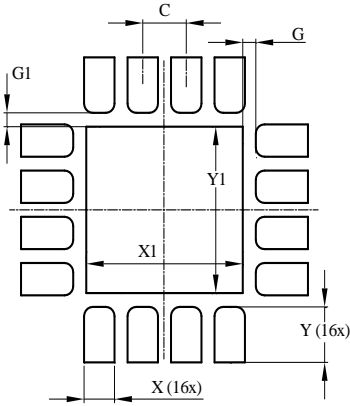


U-QFN2020-12 (Type UX)			
Dim	Min	Max	Typ
A	0.550	0.650	0.600
A1	—	0.05	—
A3	0.127 REF		
b	0.180	0.280	0.230
D	1.950	2.050	2.00
D2	0.850	0.950	0.900
E	1.950	2.050	2.00
E2	0.850	0.950	0.900
e	0.400 BSC		
L	0.250	0.350	0.300
aaa	0.10		
bbb	0.10		
ccc	0.05		
ddd	0.05		
All Dimensions in mm			

Suggested Pad Layout

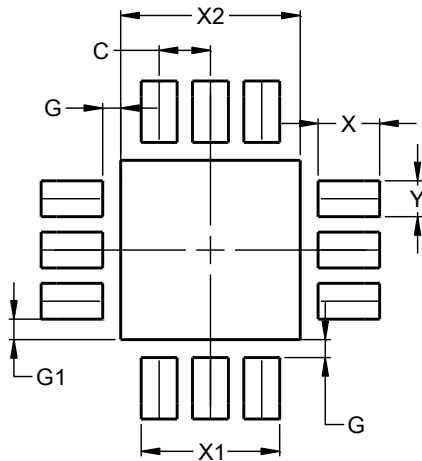
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

(1) Package Type: U-QFN3030-16 (Type B)



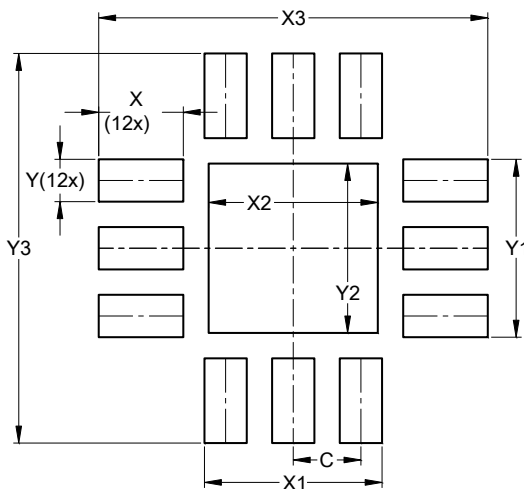
Dimensions	Value (in mm)
C	0.500
G	0.150
G1	0.150
X	0.350
X1	1.800
Y	0.600
Y1	1.800

(2) Package Type: U-QFN3030-12 (Type A)



Dimensions	Value (in mm)
C	0.500
G	0.175
G1	0.200
X	0.600
X1	1.350
X2	1.750
Y	0.350
Y1	1.750

(3) Package Type: W-QFN2020-12 (Type US)/U-QFN2020-12 (Type UX)



Dimensions	Value (in mm)
C	0.400
X	0.500
X1	1.050
X2	1.000
X3	2.300
Y	0.250
Y1	1.050
Y2	1.000
Y3	2.300

Mechanical Data

U-QFN3030-16 (Type B)/U-QFN3030-12 (Type A)

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—NiPdAu Leads, Solderable per MIL-STD-202, Method 208 (e4)
- Weight: 0.016 grams (Approximate)

W-QFN2020-12 (Type US)

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.009 grams (Approximate)

U-QFN2020-12 (Type UX)

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—NiPdAu Leads, Solderable per MIL-STD-202, Method 208 (e4)
- Weight: 0.0068 grams (Approximate)

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